VS-20CUT10, VS-20CWT10FN

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RoHS

High Performance Schottky Generation 5.0, 2 x 10 A

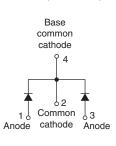




I-PAK (TO-251AA) D-PAK (TO-252AA)

common cathode 4

Anode 2 Anode Common cathode



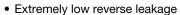
VS-20CUT10

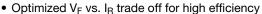
VS-20CWT10FN

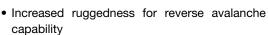
PRODUCT SUMMARY					
Package	D-PAK (TO-252AA), I-PAK (TO-251AA)				
I _{F(AV)}	2 x 10 A				
V_{R}	100 V				
V _F at I _F	0.66 V				
I _{RM} max.	4 mA at 125 °C				
T _J max.	175 °C				
Diode variation	Common cathode				
E _{AS}	54 mJ				

FEATURES

- 175 °C high performance Schottky diode
- Very low forward voltage drop







- RBSOA available
- Negligible switching losses
- Submicron trench technology
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- High efficiency SMPS
- High frequency switching
- Output rectification
- · Reverse battery protection
- Freewheeling
- DC/DC systems
- Increased power density systems

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	BOL CHARACTERISTICS VALUES UNITS						
V _{RRM}		100	V				
V _F	10 Apk, T _J = 125 °C (typical, per leg)	0.615	V				
TJ	Range	- 55 to 175	°C				

VOLTAGE RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VS-20CUT10 VS-20CWT10FN	UNITS
Maximum DC reverse voltage	V_{R}	T _J = 25 °C	100	V

VS-20CUT10, VS-20CWT10FN

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ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS		
Maximum average	per leg		50 % duty cycle at T _C = 159 °C, rectangular waveform		FO 0/ duty ovels at T 150 °C restangular visusfarm		10	
forward current	per device	I _{F(AV)}			20	Α		
Maximum peak one c	ycle	l	5 μs sine or 3 μs rect. pulse Following any rated load condition and with rated V _{RRM} applied		610	Α		
non-repetitive surge o	current per leg	I _{FSM}			110	^		
Non-repetitive avalander energy per leg	che	E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 12 mH		54	mJ		
Repetitive avalanche	current per leg	I _{AR}	Limited by frequency of operation and time pulse duration so that $T_J < T_J max$. I_{AS} at $T_J max$. as a function of time pulse (see fig. 8)		I _{AS} at T _J max.	А		

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Forward voltage drop per leg	V _{FM} ⁽¹⁾	10 A	T _J = 25 °C	0.735	0.810	V
		20 A		0.840	0.890	
		10 A	- T _J = 125 °C	0.615	0.660	
		20 A		0.730	0.770	
Reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	-	50	μΑ
		T _J = 125 °C		=	4	mA
Junction capacitance per leg	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		400	-	pF
Series inductance per leg	L _S	Measured lead to lead 5 mm from package body		8.0	-	nH
Maximum voltage rate of change	dV/dt	Rated V _R		-	10 000	V/µs

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		- 55 to 175	°C
Maximum thermal resistance, junction to case per leg	D	DC operation	2	
Maximum thermal resistance, junction to case per device	- R _{thJC}		1	°C/W
Typical thermal resistance, case to heatsink	R _{thCS}		0.3	
Approximate weight			0.3	g
			0.01	OZ.
Marking device		Case style I-PAK		JT10
		Case style D-PAK	20CWT10FN	

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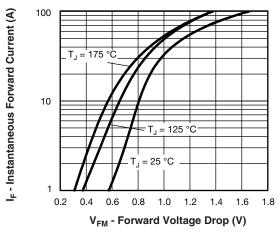


Fig. 1 - Maximum Forward Voltage Drop Characteristics

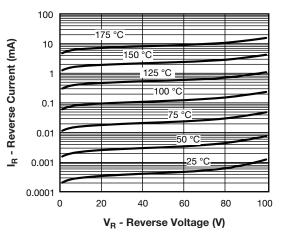


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

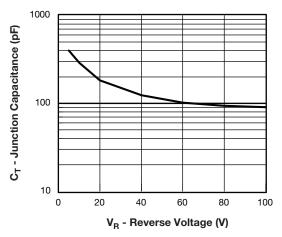


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

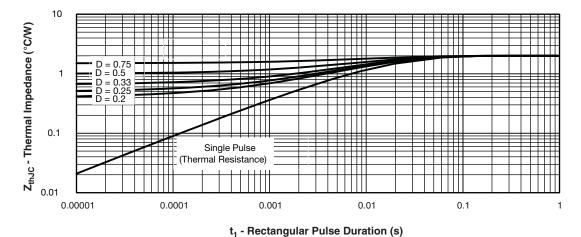


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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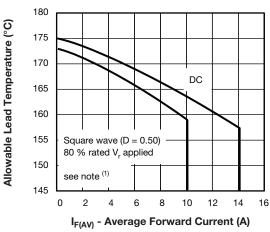


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

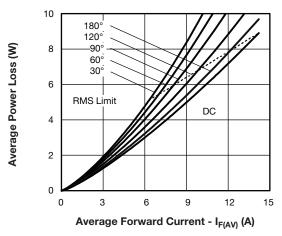
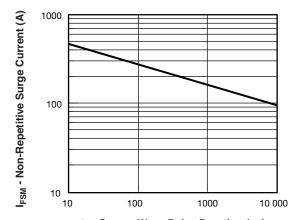


Fig. 6 - Forward Power Loss Characteristics



t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

Note

 $\begin{array}{l} \text{(1)} \ \ \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \ \text{at } (I_{F(AV)}/D) \ \text{(see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \ \text{(1 - D)}; \ I_R \ \text{at } V_{R1} = 80 \ \% \ \text{rated } V_R \end{aligned}$

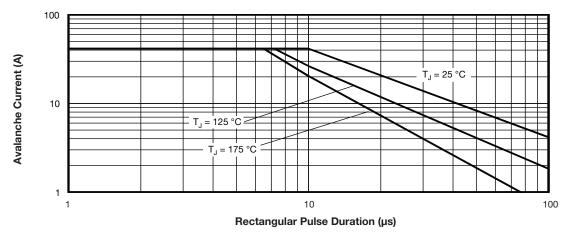


Fig. 8 - Reverse Bias Safe Operating Area (Avalanche Current vs. Rectangular Pulse Duration)

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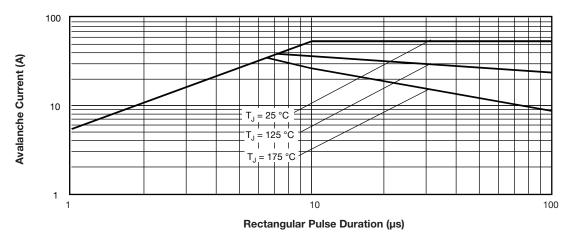
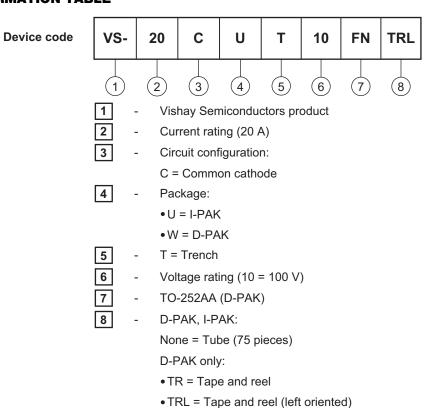


Fig. 9 - Reverse Bias Safe Operating Area (Avalanche Energy vs. Rectangular Pulse Duration)

ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS					
Dimensions	I-PAK (TO-251AA)	www.vishay.com/doc?95024			
Dimensions	D-PAK (TO-252AA)	www.vishay.com/doc?95448			
Part marking information	I-PAK (TO-251AA)	www.vishay.com/doc?95025			
	D-PAK (TO-252AA)	www.vishay.com/doc?95059			
Packaging information		www.vishay.com/doc?95033			
SPICE model		www.vishay.com/doc?95041			

• TRR = Tape and reel (right oriented)

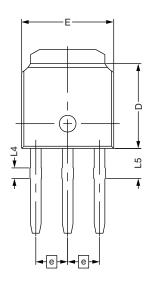
Revision: 02-Nov-11 5 Document Number: 94651

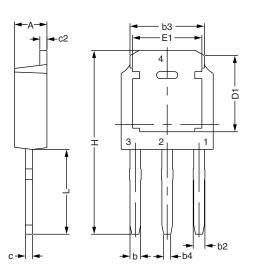


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I-PAK - S

DIMENSIONS FOR I-PAK - S in millimeters





SYMBOL	DIMENSIONAL REQUIREMENTS			
STMBOL	MIN.	NOM.	MAX.	
E	6.40	6.60	6.70	
L	3.98	4.13	4.28	
L4	0.66	0.76	0.86	
L5	1.96	2.16	2.36	
D	6.00	6.10	6.20	
Н	11.05	11.25	11.45	
b	0.64	0.76	0.88	
b2	0.77	0.84	1.14	
b3	5.21	5.34	5.46	
b4	0.41 0.51		0.61	
е	2.286 BSC			
Α	2.20	2.30	2.38	
С	0.40	0.50	0.60	
c2	0.40 0.50 0.6		0.60	
D1	5.30		-	
E1	4.40	-	-	

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Revision: 02-Oct-12 Document Number: 91000